



## **High Temperature Silicon Capacitor**

The IPDiA Technology offers industry leading performances relative to failure rate with a FIT<0.017.

This technology also offers high reliability, up to 10 times better than alternative capacitor technologies & eliminates cracking phenomena.

This silicon based technology is RoHS compliant and compatible with lead free reflow soldering process.

### **Key Applications**

- All Applications up to 200°C, such as Military, Aerospace, Automotive Industry
- High Stability Applications
- Decoupling / Filtering / Charge Pump (ie. Motor Management, Temperature Sensors)
- Devices with Battery Operations
- Replacement of X7R and C0G Pump
- Downsizing

# HTSC0603 100nF 935.132.425.610





### **Key Features**

- High Stability up to 200°C;
  - Temperature <±1% (-55 to +200°C)
  - Voltage < 0.1 % / V</li>
  - Negligible Capacitance Loss through Ageing
- Unique High Capacitance in EIA/0201 Package Size, up to
- High Reliability (FIT < 0.017 parts / billion hours)
- Low Leakage Current Down to 100pA
- Low ESL and Low ESR
- Suitable with Lead Free Reflow-Soldering

### Part Number

935.132. **B. 2** Breakdown Size: Unit: ie. 10nF/0201 case (HTSC type) → 935.132.423.510 Voltage: 2 = 1005 0 = 10f5 = 1n3 = 0201 4 = 11V1 = 0.1p6 = 10n7 = 30V 4 = 04027 = 0.1u2 = 1p3 = 10p8 = 1u

Parameters	Value
Capacitance Range	1.5nF
Capacitance Tolerances	±15%
Operating Temperature Range	-55°C to 150°C
Storage Temperatures	-70°C to 165°C
Temperature Coefficient	<±0.5%, from -55°C to +150°C
Breakdown Voltage (BV)	11VDC
Capacitance Variation Vs. RVDC	0.1% <i>N</i> (from 0 V to RVDC)
Equivalent Serial Inductor (ESL)	Max 100pH
Equivalent Serial Resistor (ESR)	Max 200mΩ
Insulation Resistance	100GΩ min @ 3V, from -55°C to +150°C
Ageing	Negligible, < 0.001% / 1000h
Reliability	FIT < 0.017 parts / billion hours
Capacitor Height	Max 400μm